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Visible to near infrared conversion in Ce3+-Yb3+ Co-doped YAG ceramics

Jumpei Ueda and Setsuhisa Tanabe

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Visible to near infrared conversion in Ce$^{3+}$–Yb$^{3+}$ Co-doped YAG ceramics

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In Ce$^{3+}$–Yb$^{3+}$ co-doped Y$_3$Al$_5$O$_{12}$ (YAG) ceramics, possibility of quantum cutting mechanism converting one visible photon into two NIR photons with optimum quantum efficiency approaching 200% have been investigated. In this material, Yb$^{3+}$ emissions due to the $^2F_{5/2}$–$^2F_{7/2}$ in the range of 1 μm were observed upon the excitation of 5d level of Ce$^{3+}$. In addition, excitation spectra of Yb$^{3+}$ emission corresponded to that of Ce$^{3+}$ emission completely. Lifetime of the 5d level of Ce$^{3+}$ decreased with increasing Yb$^{3+}$ content. These results indicate the energy transfer (ET) from the 5d levels of Ce$^{3+}$ to the $^5F_{5/2}$ level of Yb$^{3+}$. In (Y$_{0.945}$Ce$_{0.005}$Yb$_{0.005}$)$_3$Al$_5$O$_{12}$ sample, the directly measured quantum yield (QY) of Yb$^{3+}$ emission upon the excitation of 5d level of Ce$^{3+}$ was about 12% and lower than QY (96%) that estimated from the ET efficiency which was calculated with the measured lifetime of Ce$^{3+}$. © 2009 American Institute of Physics. [DOI: 10.1063/1.3194310]

I. INTRODUCTION

Luminescent materials doped with rare earth ions are used for many devices such as optical amplifiers in telecommunication, phosphors for white light emitting diodes (LEDs), displays, and so on. Recently, they also have attracted a great interest for photovoltaic applications to improve solar cell efficiency by modifying solar spectrum. Figure 1 shows the solar spectrum and the spectral response of crystalline silicon solar cell. Crystal silicon (c-Si) solar cells most effectively convert photons of energy close to the semiconductor band gap. The mismatch between the incident solar spectrum and the spectral response of solar cells is one of the main reasons to limit the cell efficiency. The efficiency limit of the c-Si have been estimated to be 29% by Shockley and Queisser. However, this limit is estimated to be improved up to 38.4% by modifying the solar spectrum by a quantum cutting (downconverting) phosphor which converts one photon of high energy into two photons of lower energy.

The phenomenon such as the quantum cutting or the downconversion of rare earth ions have been investigated since Dexter$^4$ reported the possibility of a luminescent quantum yield greater than unity in 1957. In the past, the quantum cutting from a vacuum ultraviolet photon to visible photons for Pr$^{3+}$, Gd$^{3+}$, Gd$^{3+}$–Eu$^{3+}$, and Er$^{3+}$–Tb$^{3+}$ had been studied. Recently, a new quantum cutting phenomenon from visible photon shorter than 500 nm to two infrared photons for Tb$^{3+}$–Yb$^{3+}$,$^{10-11}$ Pr$^{3+}$–Yb$^{3+}$, and$^{14}$ Tm$^{3+}$–Yb$^{3+}$ has been reported. The Yb$^{3+}$ ion is suitable as an acceptor and emitter because luminescent quantum efficiency of Yb$^{3+}$ is close to 100% and the energy of the only excited level of Yb$^{3+}$ (~1.2 eV) is roughly in accordance with the band gap of Si (~1.1 eV). However, absorption transitions of Pr$^{3+}$, Tb$^{3+}$, and Tm$^{3+}$ as a donor are due to forbidden f–f transitions. Therefore, the absorption linewidth and cross sections are not so wide and large, respectively. On the other hand, optical transitions of Ce$^{3+}$ in the UV to visible regions are due to allowed f–d transitions. As a result the absorption linewidth and cross sections are wide and large, respectively. In addition, the Ce$^{3+}$-doped Y$_3$Al$_5$O$_{12}$ (YAG), used as a phosphor for white LED, has broad absorption bands in the range of 300–500 nm due to strong ligand field and high luminescent quantum efficiency.$^{16,17}$ Therefore, the Ce$^{3+}$ ions in the YAG can be suitable as an excellent sensitizing donor for down conversion materials of Si solar cells.

In this study, Ce$^{3+}$–Yb$^{3+}$-codoped YAG ceramics were prepared and the energy transfer (ET) including down conversion mechanism in Ce$^{3+}$–Yb$^{3+}$ codoped YAG ceramics have been evaluated by the photoluminescence (PL), the photoluminescence excitation (PLE), the lifetime and the quantum yield (QY), which was measured directly using an integrating sphere.

II. EXPERIMENT

Polycrystalline YAG ceramics with composition of (Y$_{0.995-x}$Ce$_{0.005}$Yb$_x$)$_3$Al$_5$O$_{12}$ ($x=0$, 0.005, 0.02, 0.05, and $^{4}$Electronic mail: j.ueda@at3.ecs.kyoto-u.ac.jp.

FIG. 1. Solar spectrum and spectral response of c-Si.

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0.1) were prepared by using reagent grade Y₂O₃ (99.99%), Al₂O₃ (99.99%), CeO₂ (99.99%), and Yb₂O₃ (99.99%) as starting materials. The powders were mixed well with tetraethyl orthosilicate (0.5 wt %) in an alumina mortar to facilitate solid state reaction, pressed into a pellet of 20 mm diameter and sintered at 1600 °C for 6 h. The first obtained polycrystalline pellets were crushed, pressed and sintered again to obtain complete single phase of YAG. The crystal phases of obtained samples were identified by an x-ray diffraction (XRD) measurement (Shimadzu, XRD6000). For the PL spectra, samples were excited by using 450 nm light that was obtained by combining a band pass filter and a Xe lamp (Asahi Spectra Co., Ltd., MAX-302). The luminescence spectra were measured with a monochromator (Nikon, G250) and a Si photodiode (Electro-Optical System Inc., S-025-H). The obtained PL spectra were calibrated by a standard halogen lamp (Labsphere, OGL-600). In the PLE spectra measurement monitoring near infrared luminescence, the luminescence was detected by combining an 850 nm short cut filter and an InGaAs photodiode (Electro-Optical System Inc., IGA-010-H) photodiode. Samples were excited by monochromatic light obtained by combining the Xe lamp (350–800 nm) and the monochromator. For the PLE spectra monitoring visible luminescence, a 550 nm bandpass filter and the Si photodiode were used. For the luminescent decay measurement, samples were excited by using a 466 nm dye (Exciton, LD466) laser pumped with a nitrogen laser pulse excitation. The decay curves of fluorescence at 550 and 1030 nm were detected by a high-speed silicon detector (Thorlabs, Inc., DET110) and averaged on a digital oscilloscope (Yokogawa, DL1620). The decay curves of fluorescence at 550 and 1030 nm were fitted as the ratio of the emission photon number to the absorption photon number. For the YQ of emission upon the excitation of Ce³⁺:5d level, the PL spectra were measured under the 440 nm LD excitation (Nichica, NDHB510APA) by using an integrating sphere (Labsphere) which was connected to a charge coupled device (CCD) detector of visible range (Ocean Optics, USB2000) and a CCD detector of infrared range (Ocean Optics, USB2000+) with an optical bifurcated fiber of 400 μm core. The obtained PL spectra were calibrated by using the standard halogen lamp and an auxiliary lamp (Labsphere, AUX-30), and then the total radiant flux and photon distribution were obtained. The QY was evaluated as the ratio of the emission photon number to the absorption photon number. For the QY of emission upon the excitation of Yb³⁺, the 935 nm laser diode (LD) (Qphotonics, QLD-945-100S) was used as excitation.

III. RESULTS

A. YAG samples

The XRD patterns of obtained samples are shown in Fig. 2. The XRD patterns of all samples almost corresponded to that of the YAG. The XRD peaks were slightly shifted to higher angle (2θ) with increasing Yb³⁺ content (inset in Fig. 2).

B. Optical property of Ce³⁺ and Yb³⁺ in YAG

1. Photoluminescence and photoluminescence excitation

Figure 3 shows the PL spectrum by 450 nm excitation and the PLE spectra monitoring 550 and 1030 nm of the sample with x = 0.05 composition. The emission bands peaked at 550 nm (Ce³⁺:5d-4f) and 1030 nm (Yb³⁺:2F₁₅/₂→2F₇/₂) were observed by exciting the 5d level of Ce³⁺ with 450 nm light. For the PLE spectrum monitoring 550 nm, the broad excitation bands were located at 330 and 450 nm. For the PLE spectrum monitoring 1030 nm, a broad excitation band located at 450 nm was also observed. These two PLE spectra were consistent between 400 and 500 nm.

2. Decay curves

Figure 4 shows the decay curves of Ce³⁺ emission at 540 nm under the 466 nm dye laser. Each decay curve was fitted by the following single exponential function:

\[ I = I_0 \exp(-t/\tau_{\text{decay}}). \]  

(1)

It can be seen that the decay times were decreased with increasing Yb³⁺ content. Figure 5 shows the decay curves of emission at 1030 nm due to Yb³⁺ transition (3F₅/₂→2F₇/₂). In this measurement, both rise and decay components were observed. Each decay curve was fitted by the following double exponential function:

\[ I = a_1 \exp(-t/\tau_1) + a_2 \exp(-t/\tau_2). \]
$I = I_0 \{ \exp(-t/\tau_{\text{decay}}) - \exp(-t/\tau_{\text{rise}}) \}$.  \hfill (2)

**IV. TOTAL RADIANT FLUX**

Figure 6 shows the total radiant flux spectra of some samples by 440 nm LD excitation. In the sample with $x=0$ composition, the intense emission at around 540 nm was observed, while no emission at around 1030 nm was observed. The intensity of emission at around 540 nm was decreased with increasing Yb$^{3+}$ content, while that at around 1030 nm was increased with increasing Yb$^{3+}$ content until $x=5$ composition. Figure 7 shows the radiant flux spectra of samples in the range of near infrared by 935 nm LD excitation.

**V. DISCUSSIONS**

**A. YAG samples**

From the obtained XRD peaks, the lattice constant, $a$, of the YAG ceramics was estimated by the following equation that combined the Bragg's equation with a relation of cubic lattice constant with the Miller's indices:

$$a = \frac{\lambda}{2 \sin \theta} \sqrt{h^2 + k^2 + l^2},$$  \hfill (3)

where $\lambda$ is the wavelength of Cu $K_\alpha$ radiation, $(h,k,l)$ is the Miller’s indices and $\theta$ is the angle of diffraction peak. Figure 8 shows the calculated lattice constant and reference crystal of $Y_3Al_5O_{12}$:YAG$^{18}$ and Yb$_3$Al$_5$O$_{12}$:YBAG$^{19}$. The lattice constant of obtained YAG were decreased with increasing Yb$^{3+}$ content following Vegard’s law. Therefore, it was confirmed that Yb$^{3+}$ ions were incorporated into YAG crystal.

**B. Optical property of Ce$^{3+}$ and Yb$^{3+}$ in YAG**

1. **Energy transfer from Ce$^{3+}$ to Yb$^{3+}$**

Results of the PL and PLE spectra of the sample with $x=0.05$ composition in Fig. 3 indicated evidence of energy transfer from the 5$d$ levels of Ce$^{3+}$ to the $2F_{5/2}$ level of Yb$^{3+}$. The excitation bands of Ce$^{3+}$ correspond to the peak energy of solar spectrum, which is in a range of low spectral response of c-Si. In addition, the emission band peaked at 1030 nm corresponds to a range of high spectral response. Therefore, the ET from Ce$^{3+}$ to Yb$^{3+}$ in YAG ceramics is suitable for solar spectrum convertor from viewpoint spectral characteristics of the PL and the PLE. From decreasing of lifetime of Ce$^{3+}$:5$d$ level with increasing Yb$^{3+}$ content, it is considered that energy transfer from Ce$^{3+}$ to Yb$^{3+}$ occurred. The total decay rate ($W_{\text{tot}}$) of 5$d$ levels in Ce$^{3+}$ single doped YAG sample is given by

**FIG. 5.** Yb$^{3+}$ content variation of decay curve, which monitored emission from the $2F_{5/2}$ of Yb$^{3+}$ by 466 nm excitation.

**FIG. 6.** Yb$^{3+}$ content variation total radiant flux spectra by 440 nm excitation.

**FIG. 7.** Yb$^{3+}$ content variation total radiant flux spectra by 935 nm excitation.
$W_{\text{tot}} = A + W_{\text{MP}} = \tau_{\text{Ce}}^{-1}$, \hspace{1cm} (4)

where $A$ is the radiative rate, $W_{\text{MP}}$ is the multiphonon relaxation rate, and $\tau_{\text{Ce}}$ is the lifetime of 5$d$ level in Ce$^{3+}$ single doped YAG. In Ce$^{3+}$, Yb$^{3+}$-codoped YAG, the extra decay pathway from 5$d$ level of Ce$^{3+}$ to $^2F_{5/2}$ level of Yb$^{3+}$ was generated. Therefore, the total decay rate is given by

$W_{\text{tot}} = A + W_{\text{MP}} + W_{\text{ET}} = \tau_{\text{Ce,Yb}}^{-1}$, \hspace{1cm} (5)

where $W_{\text{ET}}$ is the energy transfer rate and $\tau_{\text{Ce,Yb}}$ is the lifetime of 5$d$ level in Ce$^{3+}$–Yb$^{3+}$ codoped YAG. Therefore the energy transfer efficiency is given by

$$\eta_{\text{ET}} = \frac{W_{\text{ET}}}{A + W_{\text{MP}} + W_{\text{ET}}} = 1 - \frac{\tau_{\text{Ce,Yb}}}{\tau_{\text{Ce}}}. \hspace{1cm} (6)$$

Figure 9 shows the Yb$^{3+}$ content dependence of lifetime for the 5$d$ level of Ce$^{3+}$ and the ET efficiency from the 5$d$ level of Ce$^{3+}$ to the $^2F_{5/2}$ of Yb$^{3+}$. The lifetime decreased with increasing Yb$^{3+}$ content, the ET efficiency increased with increasing Yb$^{3+}$ content. The ET efficiency exceeded about 50% above $x=0.05$ composition. Therefore the quantum yield of Yb$^{3+}$ will be over 100% if ideal quantum cutting occurred as the equation given by

$$QY = 2\eta_{\text{yb}}\eta_{\text{ET}}. \hspace{1cm} (7)$$

where $\eta_{\text{yb}}$ is the emission quantum efficiency of Yb$^{3+}$, usually about 100% because of low multiphonon relaxation rate due to large energy gap to the next lower level, the ground state. In the sample with $x=0.05$ composition, the QY was estimated high value (96%).

VI. TOTAL RADIANT FLUX

From the total radiant flux spectrum by 440 nm LD excitation, the photon distribution spectrum can be obtained. Therefore the emission and absorption photon number was estimated, and then the quantum efficiency was calculated. Figure 10 shows the Yb$^{3+}$ content dependences of the QY of Ce$^{3+}$ emission at around 550 nm and that of Yb$^{3+}$ emission at around 1030 nm. The QY of Ce$^{3+}$ emission decreased and that of Yb$^{3+}$ emission increased with increasing Yb$^{3+}$ content. The maximum value of QY of Yb$^{3+}$ was 12.8% in the $x=0.05$ sample and lower than that estimated from the ET efficiency, which was calculated with the measured lifetime of Ce$^{3+}$:5$d$ level. It is considered that other nonradiative processes existed. From the radiant flux spectrum by 935 nm LD excitation, the QY of Yb$^{3+}$ was calculated. Figure 11 shows the Yb$^{3+}$ content dependence of QY of the Yb$^{3+}$ emission by 935 nm LD excitation. At least the QY indicated higher value than 80% until $x=0.05$. Therefore it is considered that the nonradiative processes are not due to concentration quenching of Yb$^{3+}$.

VII. ENERGY TRANSFER MECHANISM

Figure 12 shows the Yb$^{3+}$ content dependence of rise and decay time of the Yb$^{3+}$ emission by 466 nm excitation.
The decay time decreased at x=0.1 composition. It is considered that concentration quenching of Yb\(^{3+}\) occurred. The rise time should correspond to relaxation time from the 5d levels of Ce\(^{3+}\) to the \(2F_{7/2}\) of Yb\(^{3+}\). However, the rise time was about 0.2 ms in all the samples and longer than lifetime (~100 ns) of Ce\(^{3+}\). The relaxation time estimated from measurement of decay curve by 440 nm LD excitation. These results indicated that the energy transfer from the 5d level of Ce\(^{3+}\) to the \(2F_{5/2}\) of Yb\(^{3+}\) is not through direct process. It is considered that the longer rise time is due to slow nonradiative relaxation from a charge transfer state (CTS) to the \(2F_{5/2}\) level. In Yb\(^{3+}\)-doped YAG, the charge transfer absorption and the charge transfer luminescence have been reported.\(^{20-23}\) In addition, it had been known that the emission of Ce\(^{3+}\) was quenched by the process of charge transfer state (Ce\(^{4+}\)-Yb\(^{2+}\)) in Ce\(^{3+}\)-doped crystal that consists of Yb, such as LiYbF\(_4\), YbSiO\(_5\).\(^{24-26}\) That is because the Ce\(^{3+}\) and Yb\(^{3+}\) changes to Ce\(^{4+}\) and Yb\(^{2+}\) easily. In a similar system, it was reported that Yb\(^{3+}\) IR emission in Tb\(^{3+}\)-Yb\(^{3+}\) codoped \(\text{Y}_2\text{O}_3\) by UV excitation was caused through Tb\(^{3+}\)-Yb\(^{2+}\) charge transfer state.\(^{12}\) Therefore, it is considered that the energy transfer from Ce\(^{3+}\) to Yb\(^{3+}\) may be caused through a CTS Ce\(^{4+}\)-Yb\(^{2+}\) (Fig. 13).

VIII. CONCLUSION

The energy transfer from Ce\(^{3+}\) and sensitized luminescence of Yb\(^{3+}\) in polycrystalline YAG ceramics was observed. The quantum yields of Yb\(^{3+}\) emission upon Ce\(^{3+}\) \(5d\) level excitation were lower than that value expected for the ideal quantum cutting mechanism. In addition the relaxation time, which was estimated from measurement of Yb\(^{3+}\) decay curve by 440 nm LD excitation, from 5d levels of Ce\(^{3+}\) to \(2F_{7/2}\) of Yb\(^{3+}\) was not consistent to the lifetime of Ce\(^{3+}\) estimated from measurement of Ce\(^{3+}\) decay curve by 440 nm LD excitation. From the QY of Yb\(^{3+}\) emission by 935 nm excitation, the concentration quenching did not occur until x = 0.5 Yb\(^{3+}\) concentration. Therefore, we indicated that the energy transfer from Ce\(^{3+}\) to Yb\(^{3+}\) in YAG was not direct process and has some nonradiative processes that were not the concentration quenching Yb\(^{3+}\).

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